



P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)		
	0.032 at $V_{GS} = -4.5 \text{ V}$	- 7.1			
- 20	0.040 at V _{GS} = - 2.5 V	- 6.4	16.5		
	0.053 at V _{GS} = - 1.8 V	- 5.5			

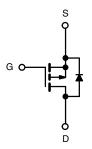
FEATURES

- Halogen-free According to IEC 61249-2-21 **Available**
- TrenchFET® Power MOSFET
- Ultra-Low On-Resistance
- Thermally Enhanced ChipFET® Package
- 40 % Smaller Footprint than TSOP-6



APPLICATIONS

Load Switch, PA Switch, and Battery Switch for Portable **Devices**



P-Channel MOSFET

D D D G G	Marking Code BO XXX Lot Traceability and Date Code Part # Code
Bottom View	Part # Code

Ordering Information: Si5401DC-T1-E3 (Lead (Pb)-free)

1206-8 ChipFET®

Si5401DC-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T	A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 20		V
Gate-Source Voltage		V _{GS}	± 8		
Continuous Drain Current /T 150 °C\d	T _A = 25 °C	- I _D	- 7.1	- 5.2	٨
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		- 5.1	- 3.7	
Pulsed Drain Current		I _{DM}	- 20		Α
Continuous Source Current ^a		I _S	- 2.1	- 1.1	
M	T _A = 25 °C	P _D	2.5	1.3	W
Maximum Power Dissipation ^a	T _A = 85 °C		1.3	0.7	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}			260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manianum lungtion to Ambient	t ≤ 5 s	R _{thJA}	40	50	°C/W	
Maximum Junction-to-Ambient ^a	Steady State	' ¹thJA	80	95		
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	15	20		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Vishay Siliconix



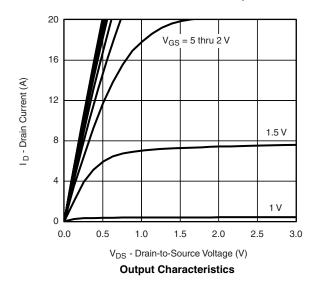
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	- 0.40		- 1.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zava Cata Valta da Busin Comuna	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current		V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 85 °C			- 5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le$ - 5 V, $V_{GS} =$ - 4.5 V	- 20			Α	
Drain-Source On-State Resistance ^a		V _{GS} = - 4.5 V, I _D = - 5.2 A		0.026	0.032		
	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 4.6 A		0.033	0.040	Ω	
		V _{GS} = - 1.8 V, I _D = - 1.9 A		0.044	0.053		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 5.2 A		20		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.1 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			16.5	25		
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -5.2 \text{ A}$		1.7		nC	
Gate-Drain Charge	Q_{gd}			3.5			
Gate Resistance	R_g	f = 1 MHz		9		Ω	
Turn-On Delay Time	t _{d(on)}			10	15		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		25	40		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		115	175	ns	
Fall Time	t _f			70	105		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.1 A, dl/dt = 100 A/μs		30	60		
Reverse Recovery Charge	Q_{rr}	$I_F = -1.1 \text{ A}$, $GI/GI = 100 \text{ A}/\mu\text{S}$		140		nC	

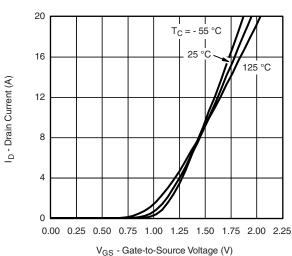
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





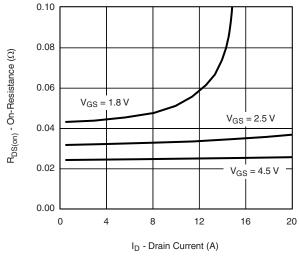
Transfer Characteristics



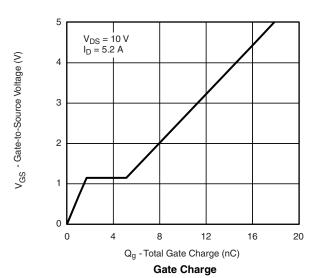




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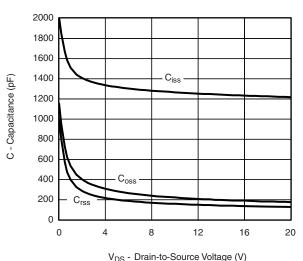


On-Resistance vs. Drain Current



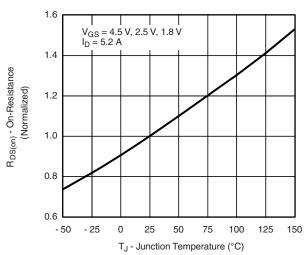
 $T_{J} = 150 \, ^{\circ}\text{C}$ $T_{J} = 125 \, ^{\circ}\text{C}$ $T_{J} = 25 \, ^{\circ}\text{C}$ $V_{SD} - \text{Source-to-Drain Voltage (V)}$

Source-Drain Diode Forward Voltage

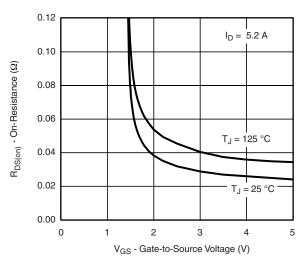


VDS - Dialii-to-Source voltage (v)





On-Resistance vs. Junction Temperature

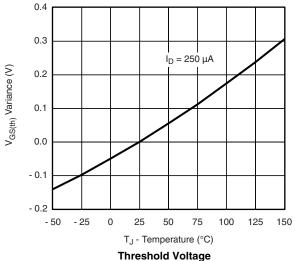


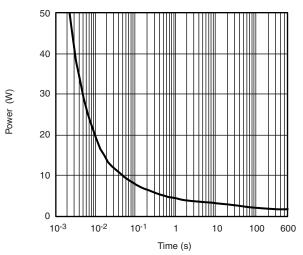
On-Resistance vs. Gate-to-Source Voltage

S - Source Current (A)

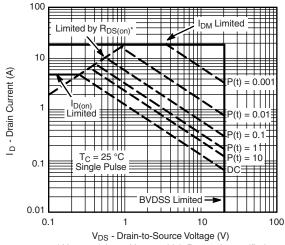
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



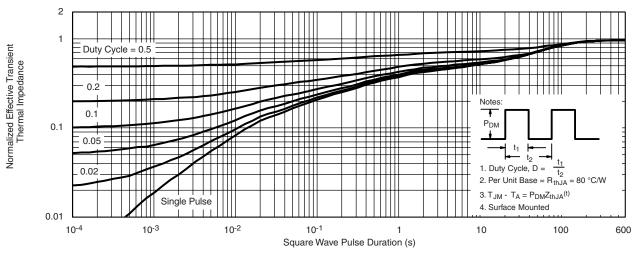






* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area



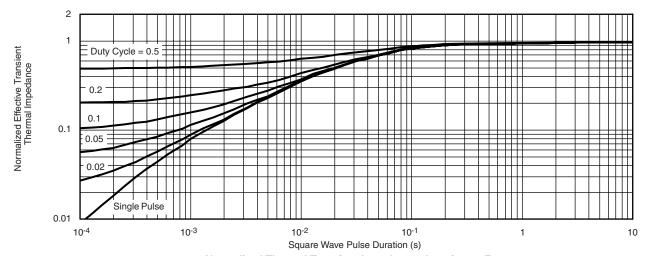
Normalized Thermal Transient Impedance, Junction-to-Ambient







TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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